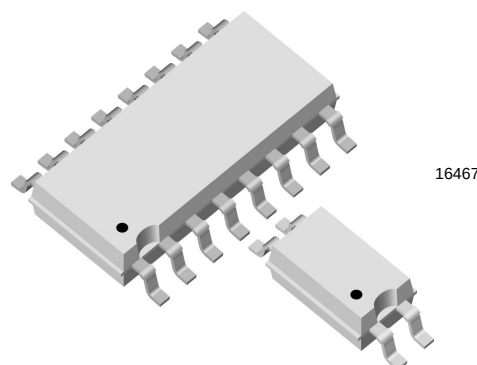


Optocoupler with Photodarlington Output

Description

The TCMD10.. Series consist of a photodarlington optically coupled to a gallium arsenide infrared-emitting diodes in an 4- lead up to 16- lead plastic Miniflat package.

The elements are mounted on one leadframe using a **coplanar technique**, providing a fixed distance between input and output for highest safety requirements.

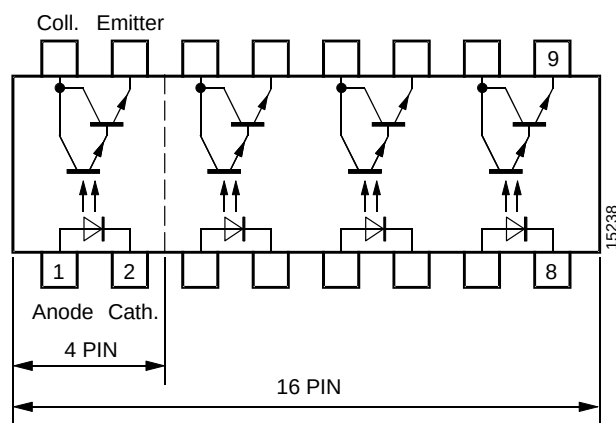


Applications

Programmable logic controllers, modems, answering machines, general applications

Features

- Low profile package (half pitch)
- AC Isolation test voltage $V_{i0} = 3.75 \text{ kV}_{\text{RMS}}$
- Low coupling capacitance of typical 0.3 pF
- Low temperature coefficient of CTR
- Wide ambient temperature range
- Underwriters Laboratory (UL) 1577 recognized, file number E-76222
- CSA (C-UL) 1577 recognized file number E- 76222 - Double Protection
- Coupling System M



Order Instruction

Ordering Code	CTR Ranking	Remarks
TCMD1000	>600%	4 Pin = Single channel
TCMD4000	>600%	16 Pin = Quad channel

Absolute Maximum Ratings

Input (Emitter)

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		V_R	6	V
Forward current		I_F	60	mA
Forward surge current	$t_p \leq 10 \mu s$	I_{FSM}	1.5	A
Power dissipation	$T_{amb} \leq 25^\circ C$	P_V	100	mW
Junction temperature		T_j	125	$^\circ C$

Output (Detector)

Parameter	Test Conditions	Symbol	Value	Unit
Collector emitter voltage		V_{CEO}	35	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	80	mA
Peak collector current	$t_p/T = 0.5, t_p \leq 10 ms$	I_{CM}	100	mA
Power dissipation	$T_{amb} \leq 25^\circ C$	P_V	150	mW
Junction temperature		T_j	125	$^\circ C$

Coupler

Parameter	Test Conditions	Symbol	Value	Unit
AC isolation test voltage (RMS)		$V_{IO}^{1)}$	3.75	kV
Total power dissipation	$T_{amb} \leq 25^\circ C$	P_{tot}	250	mW
Operating ambient temperature range		T_{amb}	-40 to +100	$^\circ C$
Storage temperature range		T_{stg}	-40 to +100	$^\circ C$
Soldering temperature		T_{sd}	235	$^\circ C$

¹⁾ Related to standard climate 23/50 DIN 50014

**Electrical Characteristics** ($T_{amb} = 25^{\circ}\text{C}$)**Input (Emitter)**

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	$I_F = 50\text{ mA}$	V_F		1.25	1.6	V
Junction capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$	C_j		50		pF

Output (Detector)

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector emitter voltage	$I_C = 100\text{ }\mu\text{A}$	V_{CEO}	35			V
Emitter collector voltage	$I_E = 100\text{ }\mu\text{A}$	V_{ECO}	7			V
Collector dark current	$V_{CE} = 10\text{ V}$, $I_F = 0$, $E = 0$	I_{CEO}			100	nA

Coupler

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector emitter saturation voltage	$I_F = 10\text{ mA}$, $I_C = 1\text{ mA}$	V_{CEsat}			0.3	V
Cut-off frequency	$I_F = 10\text{ mA}$, $V_{CE} = 5\text{ V}$, $R_L = 100\text{ }\Omega$	f_c		10		kHz
Coupling capacitance	$f = 1\text{ MHz}$	C_k		0.3		pF

Current Transfer Ratio (CTR)

Parameter	Test Conditions	Type	Symbol	Min.	Typ.	Max.	Unit
I_C/I_F	$V_{CE} = 2\text{ V}$, $I_F = 1\text{ mA}$	TCMD1000	CTR	6.0	8.0		
	$V_{CE} = 2\text{ V}$, $I_F = 1\text{ mA}$	TCMD4000	CTR	6.0	8.0		

Switching Characteristics

Parameter	Test Conditions	Symbol	Typ.	Unit
Rise time	$V_{CE} = 2 \text{ V}$, $I_C = 10 \text{ mA}$, $R_L = 100 \Omega$ (see figure 1)	t_r	300	μs
Turn-off time		t_{off}	250	μs

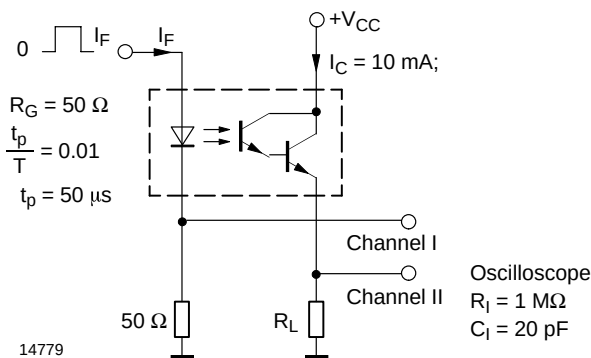


Figure 1. Test circuit, non-saturated operation

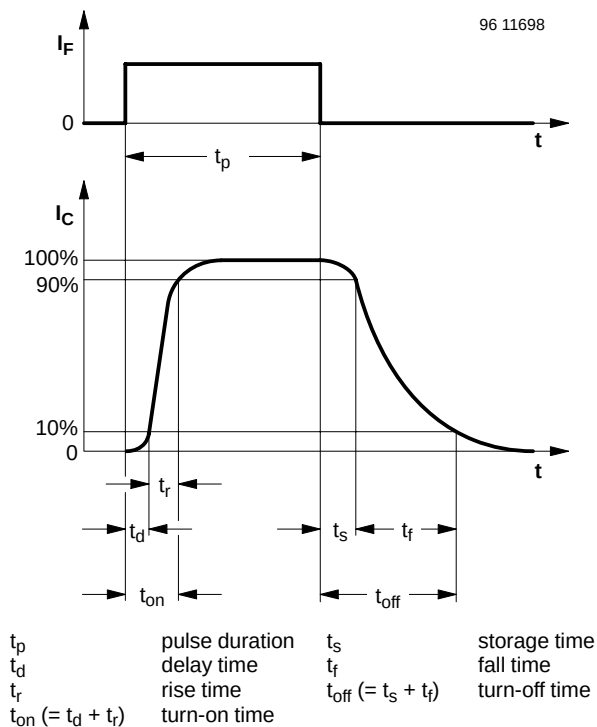


Figure 2. Switching times

Typical Characteristics ($T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified)

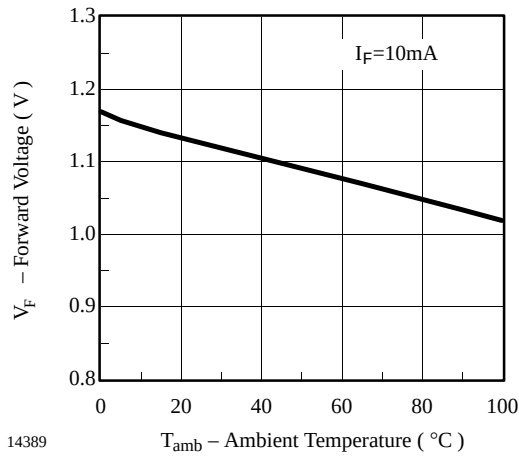


Figure 3. Forward Voltage vs. Ambient Temperature

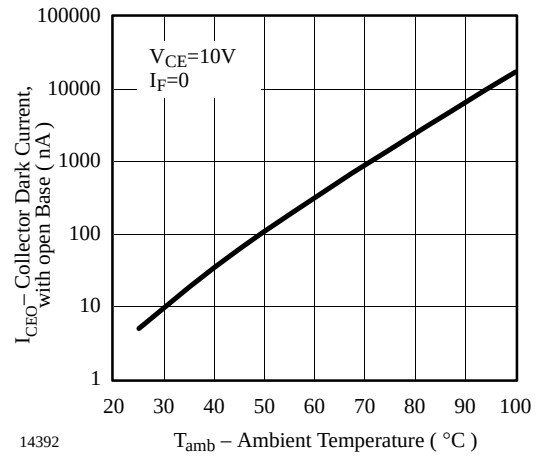


Figure 6. Collector Dark Current vs. Ambient Temperature

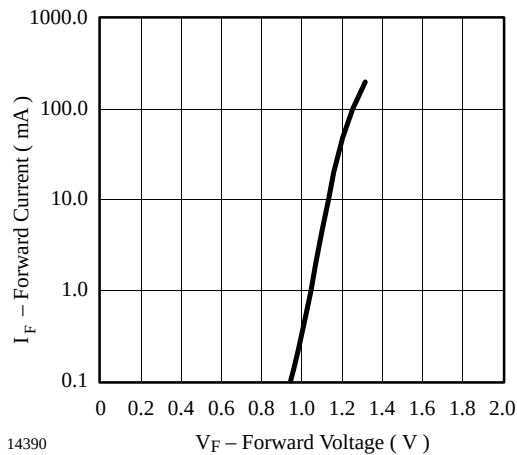


Figure 4. Forward Current vs. Forward Voltage

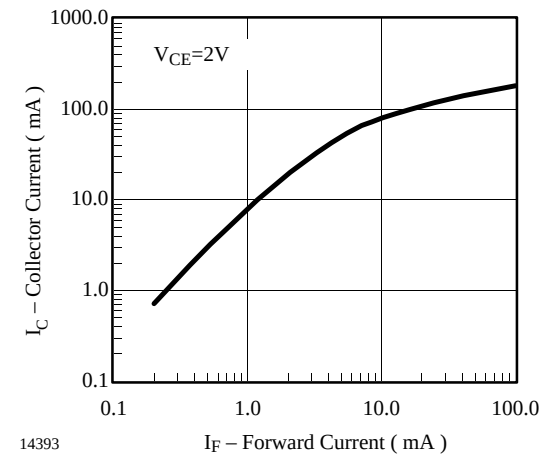


Figure 7. Collector Current vs. Forward Current

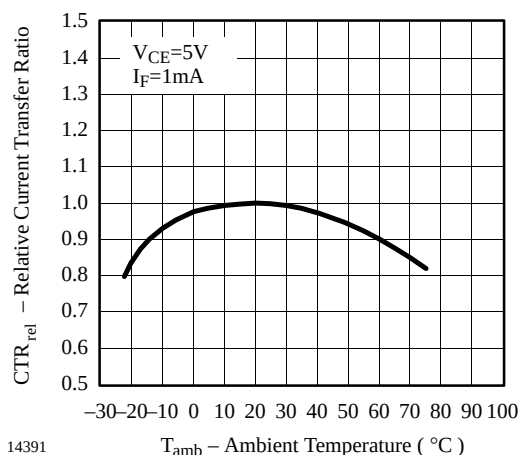


Figure 5. Relative Current Transfer Ratio vs. Ambient Temperature

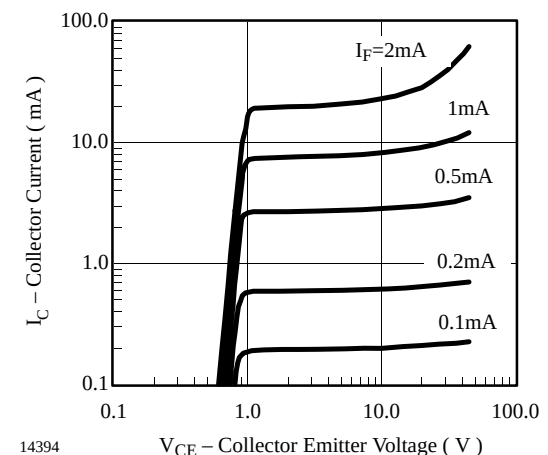


Figure 8. Collector Current vs. Collector Emitter Voltage

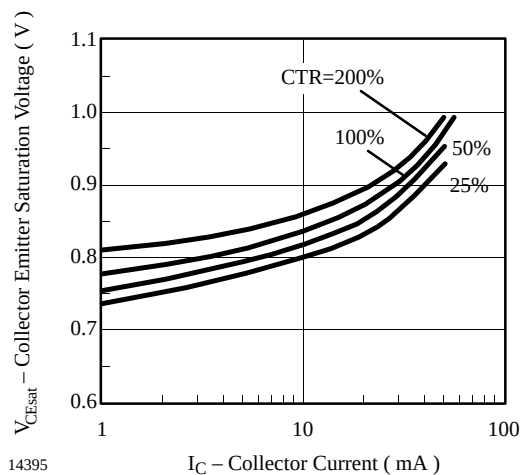


Figure 9. Collector Emitter Saturation Voltage vs. Collector Current

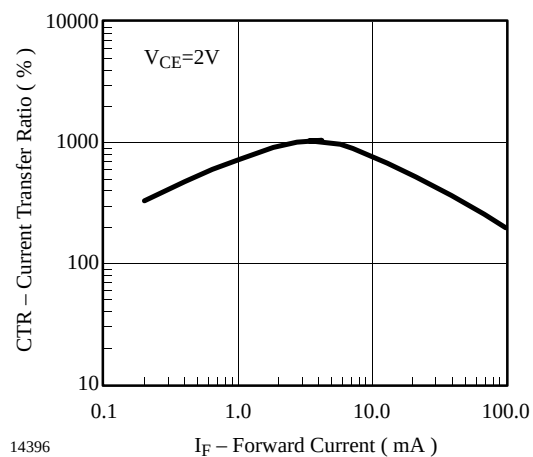


Figure 10. Current Transfer Ratio vs. Forward Current

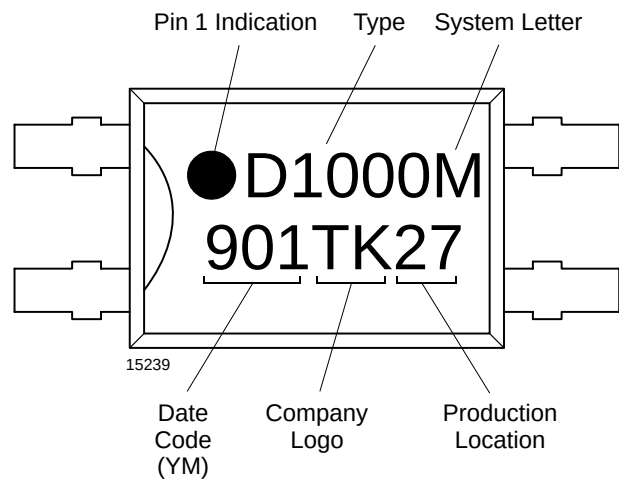
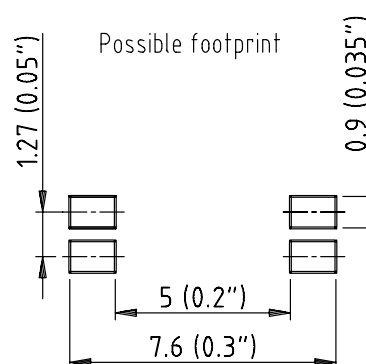
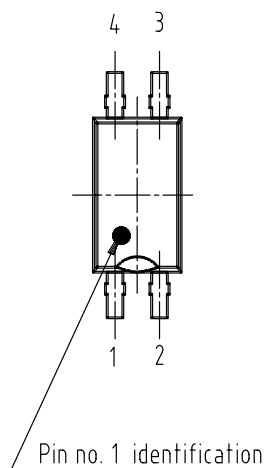
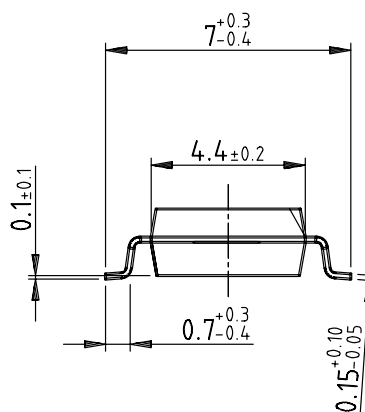
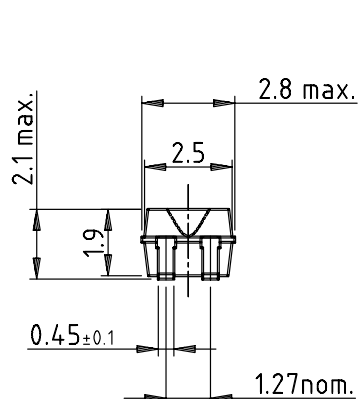
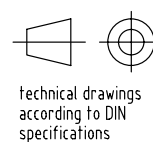


Figure 11. Marking example

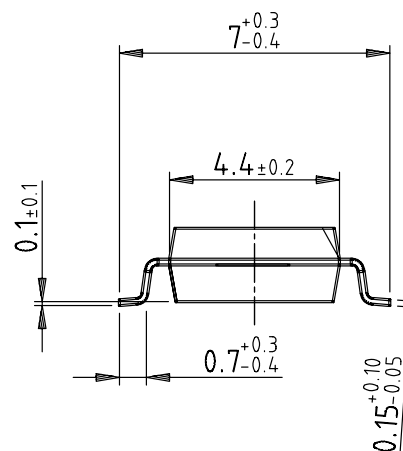
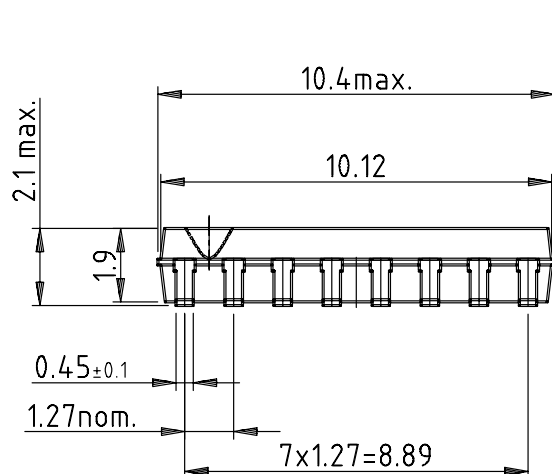
Dimensions of TCMD1... in mm



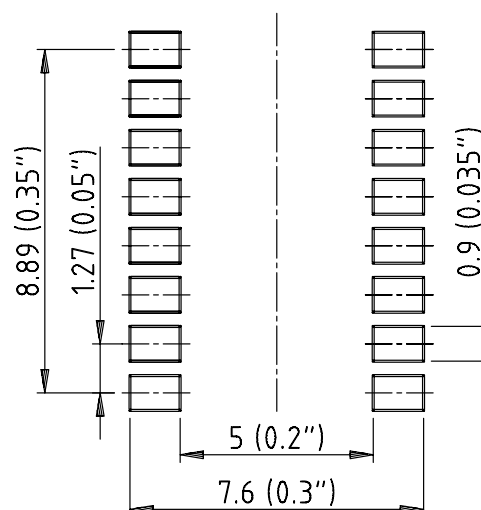
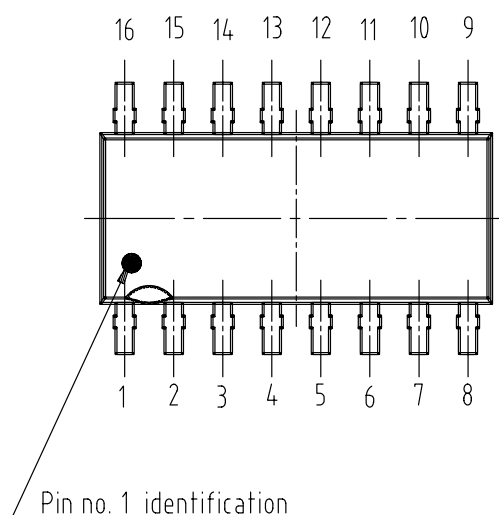
16283



Dimensions of TCMD4... in mm

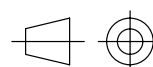


Possible footprint



Drawing-No.: 6.544-5330.03-4

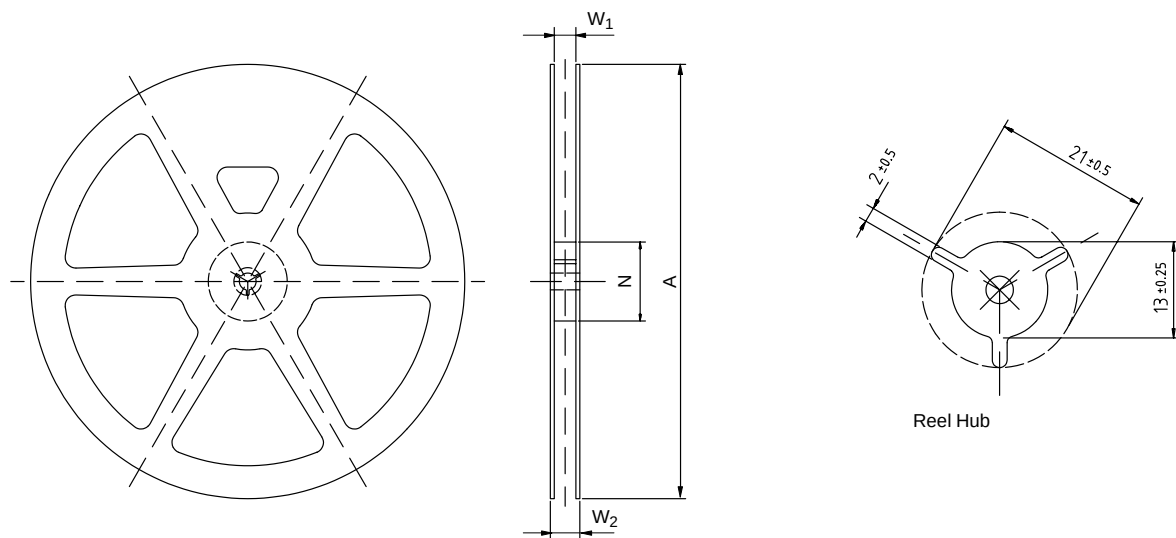
Issue: 1; 04.04.00



technical drawings
according to DIN
specifications

15226

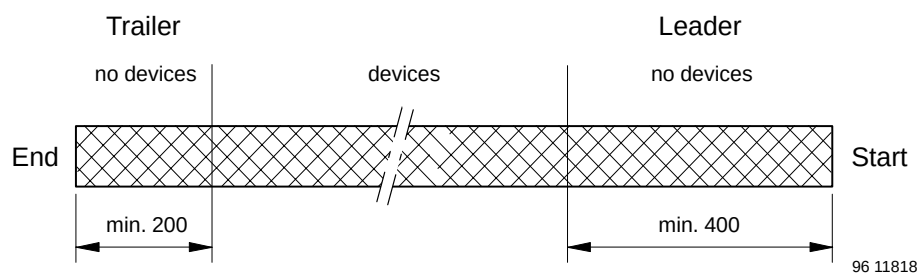
Dimensions of Reel in mm



16515

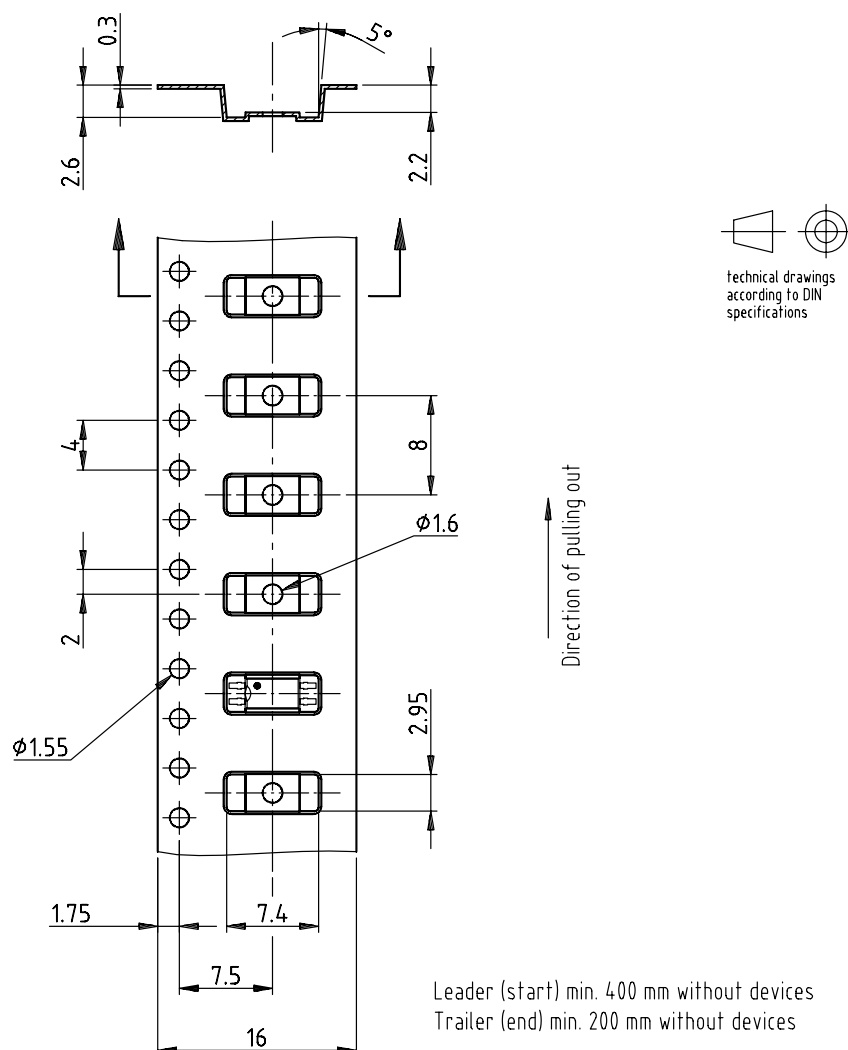
Version	Tape Width	A	N	W_1	W_2 max
G	16	330 ± 1	100 ± 1.5	$16.4 + 2$	22.4

Dimensions of Leader and Trailer in mm



96 11818

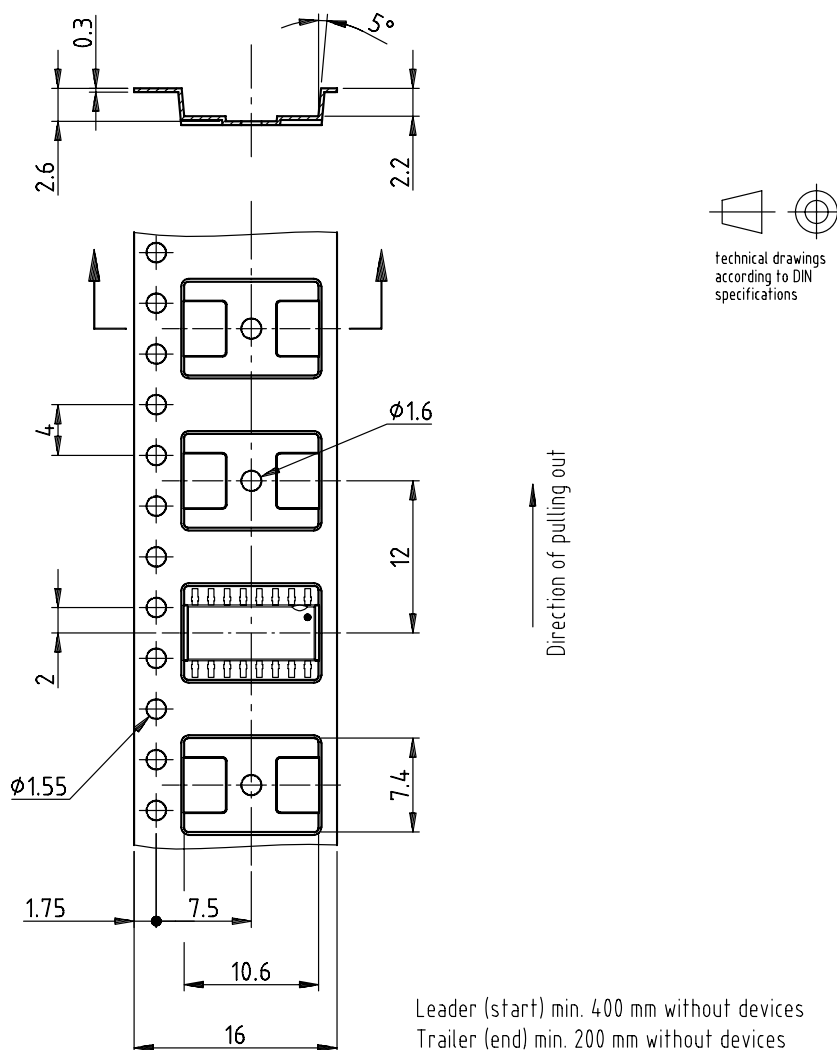
Dimensions of Tape in mm



Drawing-No.: 9.700-5253.01-4
Issue: 1; 22.11.00

16511

Dimensions of Tape in mm



Drawing-No.: 9.700-5252.01-4
Issue: 1; 22.11.00

16510



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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